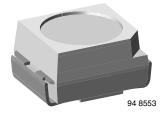


**Vishay Semiconductors** 

# High Speed Infrared Emitting Diode, 850 nm, GaAIAs Double Hetero



#### DESCRIPTION

VSMG3700 is an infrared, 850 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a PLCC-2 package for surface mounting (SMD).

#### **FEATURES**

- · Package type: surface mount
- Package form: PLCC-2
- Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75
- Peak wavelength:  $\lambda_p = 850 \text{ nm}$
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity:  $\phi = \pm 60^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- High modulation band width:  $f_c = 18$  MHz
- · Good spectral matching with Si photodetectors
- Floor life: 168 h, MSL 3, acc. J-STD-020
- · Lead (Pb)-free reflow soldering
- AEC-Q101 gualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **APPLICATIONS**

- Infrared radiation source for operation with CMOS cameras (illumination)
- · High speed IR data transmission

PRODUCT SUMMARY							
COMPONENT	l <sub>e</sub> (mW/sr)	φ <b>(deg)</b>	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)			
VSMG3700	10	± 60	850	20			

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	ORDERING CODE PACKAGING		PACKAGE FORM			
VSMG3700-GS08	Tape and reel	MOQ: 7500 pcs, 1500 pcs/reel	PLCC-2			
VSMG3700-GS18	Tape and reel	MOQ: 8000 pcs, 8000 pcs/reel	PLCC-2			

Note

• MOQ: minimum order quantity

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

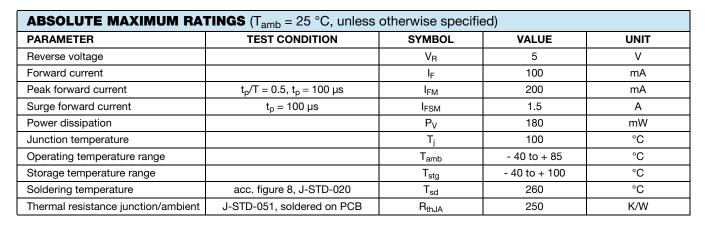
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(5-2008)

# **VSMG3700**

### Vishay Semiconductors High Speed Infrared Emitting Diode, 850 nm, GaAlAs Double Hetero



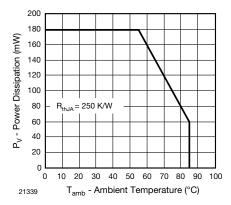


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

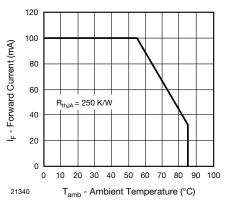


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>		1.5	1.8	V
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	V <sub>F</sub>		2.3		V
Temperature coefficient of $V_F$	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		- 1.8		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		125		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	6	10	22	mW/sr
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	l <sub>e</sub>		100		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	\$e		40		mW
Temperature coefficient of $\phi_{\text{e}}$	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		- 0.35		%/K
Angle of half intensity		φ		± 60		deg
Peak wavelength	I <sub>F</sub> = 100 mA	λρ		850		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		40		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	ΤΚλρ		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA	t <sub>r</sub>		20		ns
Fall time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		13		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f <sub>c</sub>		18		MHz
Virtual source diameter		d		0.44		mm



# **VSMG3700**

# High Speed Infrared Emitting Diode, Vishay Semiconductors 850 nm, GaAlAs Double Hetero

#### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

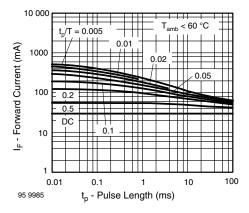


Fig. 3 - Pulse Forward Current vs. Pulse Duration

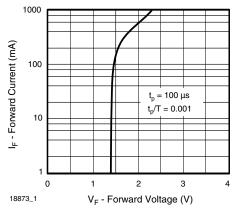


Fig. 4 - Forward Current vs. Forward Voltage

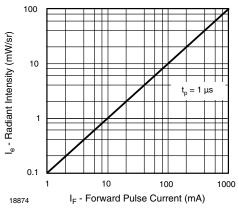


Fig. 5 - Radiant Intensity vs. Forward Current

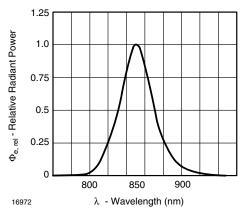


Fig. 6 - Relative Radiant Power vs. Wavelength

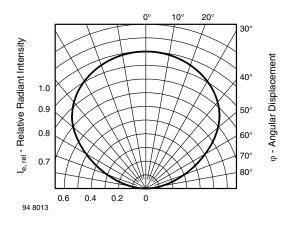
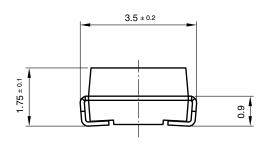


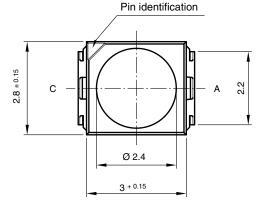
Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

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#### **PACKAGE DIMENSIONS** in millimeters

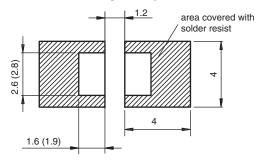




Mounting Pad Layout

technical drawings

according to DIN



Drawing-No.: 6.541-5067.01-4 Issue: 5; 04.11.08 20541

#### **SOLDER PROFILE**

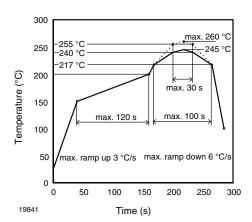


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 168 h Conditions:  $T_{amb} < 30$  °C, RH < 60 % Moisture sensitivity level 3, acc. to J-STD-020.

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



## High Speed Infrared Emitting Diode, Vishay Semiconductors 850 nm, GaAlAs Double Hetero

#### **TAPE AND REEL**

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.

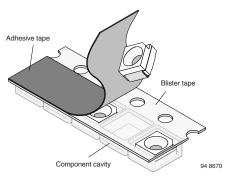


Fig. 9 - Blister Tape

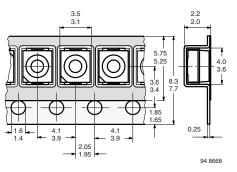
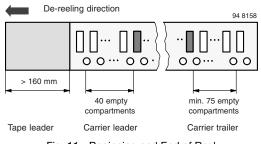
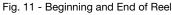


Fig. 10 - Tape Dimensions in mm for PLCC-2

#### **MISSING DEVICES**

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.





The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.

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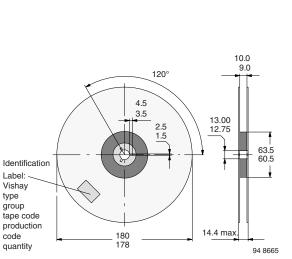


Fig. 12 - Dimensions of Reel-GS08

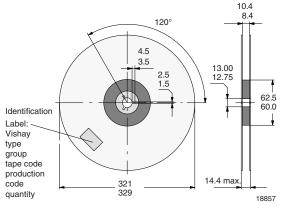


Fig. 13 - Dimensions of Reel-GS18

#### **COVER TAPE REMOVAL FORCE**

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.



Vishay

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